

Super SIDELED High-Current LED

LG A672, LP A672



Besondere Merkmale

- **Gehäusotyp:** weißes SMT Gehäuse
- **Besonderheit des Bauteils:** Abstrahlung parallel zur Platine, deshalb ideal zur Einkopplung in Lichtleiter; höherer zulässiger Betriebsstrom
- **Wellenlänge:** 570 nm (grün), 560 nm (pure green)
- **Abstrahlwinkel:** Lambertscher Strahler (120°)
- **Technologie:** GaAsP (grün), GaP (pure green)
- **optischer Wirkungsgrad:** 1,5 lm/W (grün), 0,6 lm/W (pure green)
- **Gruppierungsparameter:** Lichtstärke
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 12 mm Gurt mit 2000/Rolle, ø330 mm

Anwendungen

- Hinterleuchtung (LCD, Schalter, Tasten, Displays)
- Einkopplung in Lichtleiter
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u.ä.)

Features

- **package:** white SMT package
- **feature of the device:** radiation direction parallel to PCB, so an ideal LED for coupling in light guides; higher permissible current
- **wavelength:** 570 nm (green), 560 nm (pure green)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** GaAsP (green), GaP (pure green)
- **optical efficiency:** 1.5 lm/W (green), 0.6 lm/W (pure green)
- **grouping parameter:** luminous intensity
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 12 mm tape with 2000/reel, ø330 mm

Applications

- backlighting (LCD, switches, keys, displays)
- coupling into light guide
- interior automotive lighting. (e.g. dashboard backlighting, etc.)

Typ	Emissions- farbe	Farbe der Lichtaustritts- fläche	Lichtstärke	Lichtstrom	Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 50 \text{ mA}$ $I_V \text{ (mcd)}$	Luminous Flux $I_F = 50 \text{ mA}$ $\Phi_V \text{ (lm)}$	Ordering Code
■ LG A672-P1Q1-1	green	colorless clear	45.0 ... 90.0	190 (typ.)	Q62703-Q5000
■ LG A672-Q1R2-1			71.0 ... 180.0	350 (typ.)	Q62703-Q5001
■ LP A672-L2M2-1	pure green	colorless clear	14.0 ... 28.0	62 (typ.)	Q62703-Q5056
■ LP A672-M2P1-1			22.4 ... 56.0	110 (typ.)	Q62703-Q5057

■ Nicht für Neuentwicklungen / Not for new designs

Anm.: -1 gesamter Farbbereich

*Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe, die aus nur 3 bzw. 4 Halbgruppen besteht. Einzelne Halbgruppen sind nicht erhältlich.
In einer Verpackungseinheit / Gurt ist immer nur eine Halbgruppe enthalten.*

Note: -1 Total color tolerance range

*The standard shipping format for serial types includes a lower or upper family group of 3 or 4 individual groups. Individual half groups are not available.
No packing unit / tape ever contains more than one luminous intensity half group.*

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 100	°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 100	°C
Sperrschichttemperatur Junction temperature	T_j	+ 100	°C
Durchlassstrom Forward current	I_F	50	mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	1	A
Sperrspannung Reverse voltage	V_R	5	V
Leistungsaufnahme Power consumption	P_{tot}	160	mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient Sperrschicht/Lötpad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)	$R_{th JA}$ $R_{th JS}$	330 100	K/W K/W

Kennwerte ($T_A = 25\text{ °C}$)
Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LG	LP	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 50\text{ mA}$	λ_{peak}	572	557	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength $I_F = 50\text{ mA}$	λ_{dom}	570 ± 6	560 ± 6	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 50\text{ mA}$	$\Delta\lambda$	25	22	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V (typ.)	2ϕ	120	120	Grad deg.
Durchlassspannung ²⁾ (typ.) Forward voltage (max.) $I_F = 50\text{ mA}$	V_F V_F	2.6 3.5	2.6 2.7	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 5\text{ V}$	I_R I_R	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 50\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.11	0.11	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 50\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.07	0.05	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 50\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 2.0	- 2.0	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 50\text{ mA}$	η_{opt}	1.5	0.6	lm/W

¹⁾ Wellenlängen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelengths are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Spannungswerte werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0.1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_v (mcd)	Lichtstrom Luminous Flux Φ_v (lm)
L2	14.0 ... 18.0	50 (typ.)
M1	18.0 ... 22.4	60 (typ.)
M2	22.4 ... 28.0	75 (typ.)
N1	28.0 ... 35.5	95 (typ.)
N2	35.5 ... 45.0	120 (typ.)
P1	45.0 ... 56.0	150 (typ.)
P2	56.0 ... 71.0	190 (typ.)
Q1	71.0 ... 90.0	240 (typ.)
Q2	90.0 ... 112.0	300 (typ.)
R1	112.0 ... 140.0	380 (typ.)
R2	140.0 ... 180.0	480 (typ.)

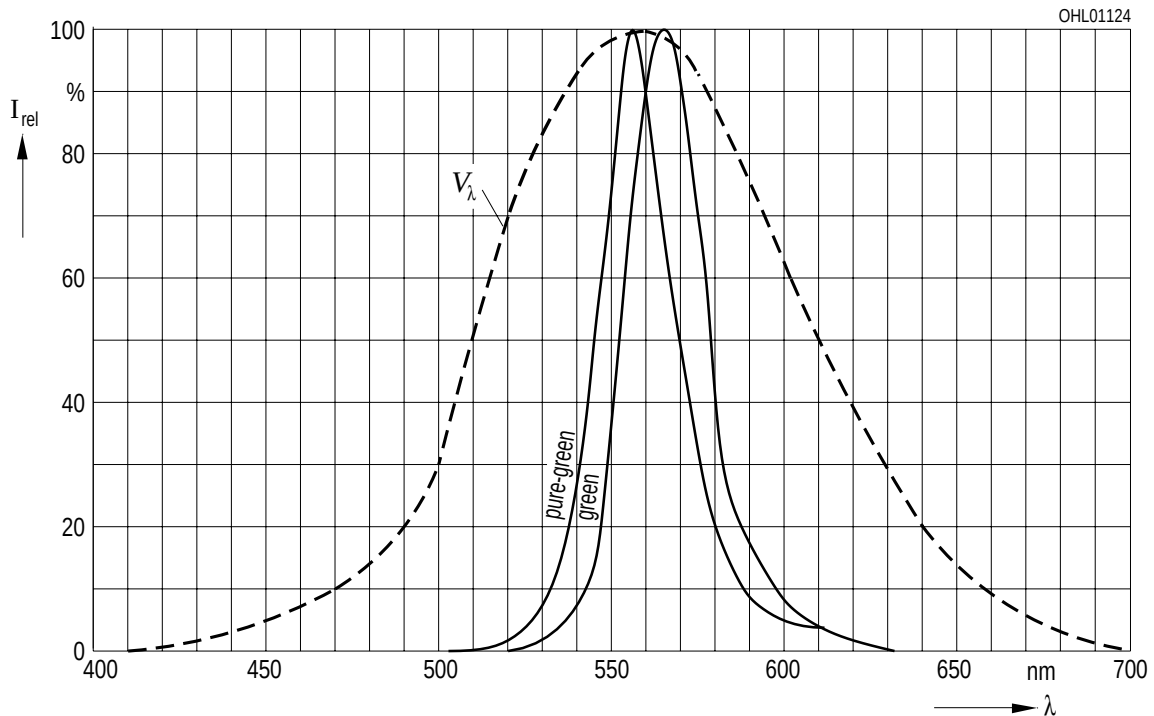
Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
 Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 50\text{ mA}$

Relative Spectral Emission

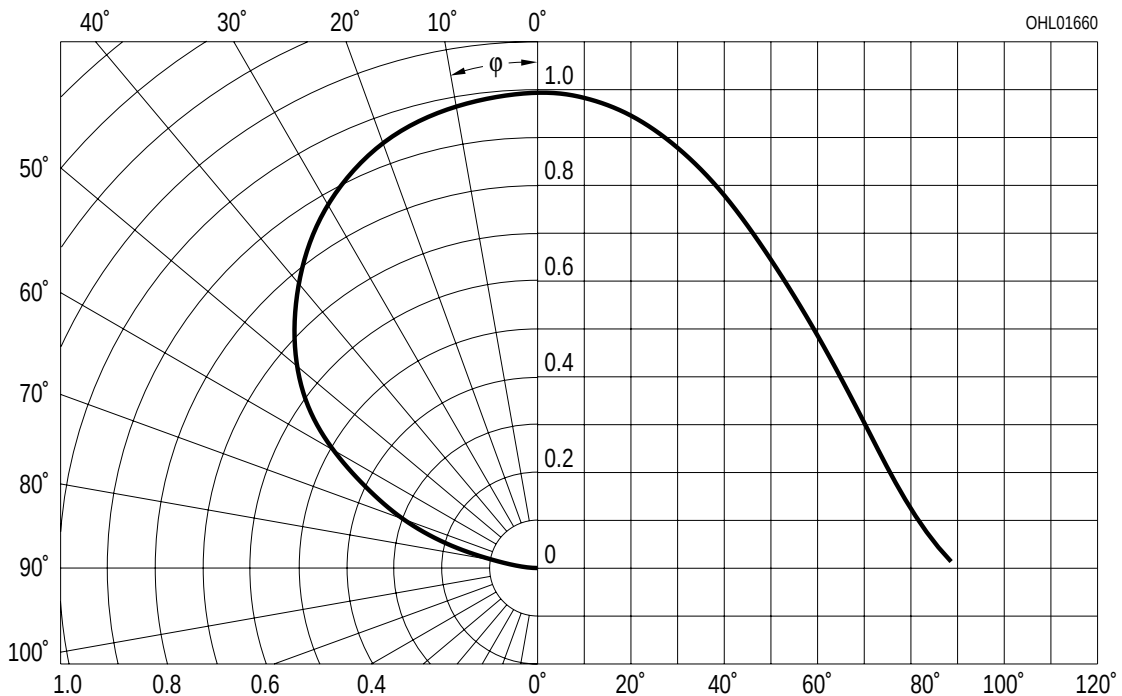
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



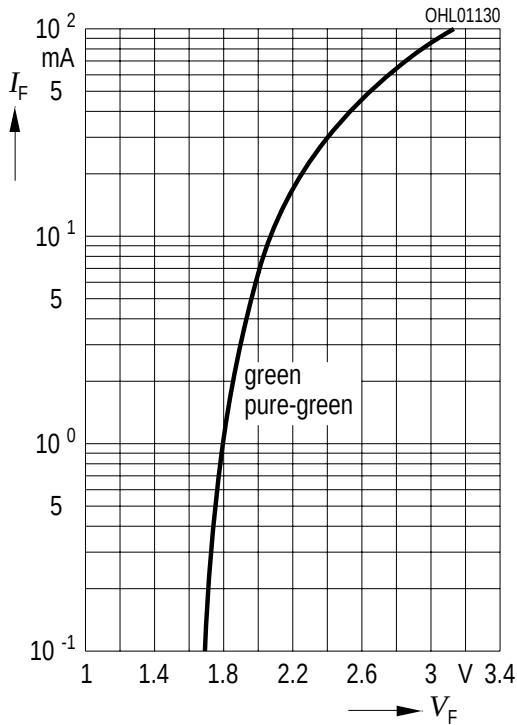
Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

Radiation Characteristic



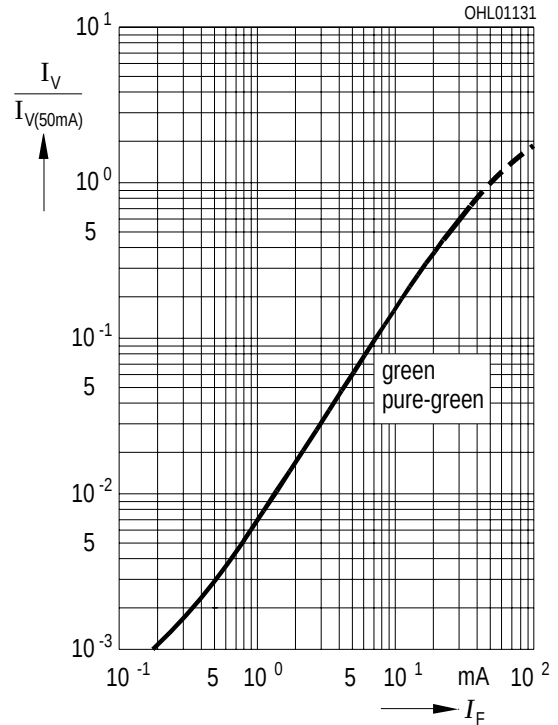
Durchlassstrom $I_F = f(V_F)$
Forward Current

$T_A = 25^\circ\text{C}$

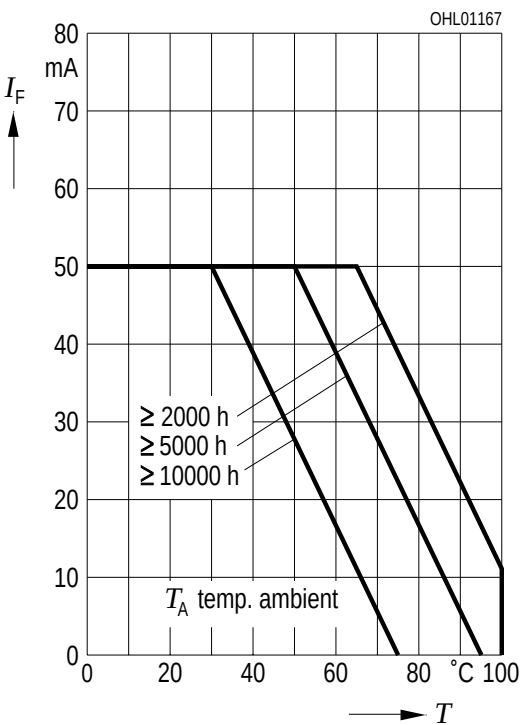


Relative Lichtstärke $I_V/I_{V(50\text{ mA})} = f(I_F)$
Relative Luminous Intensity

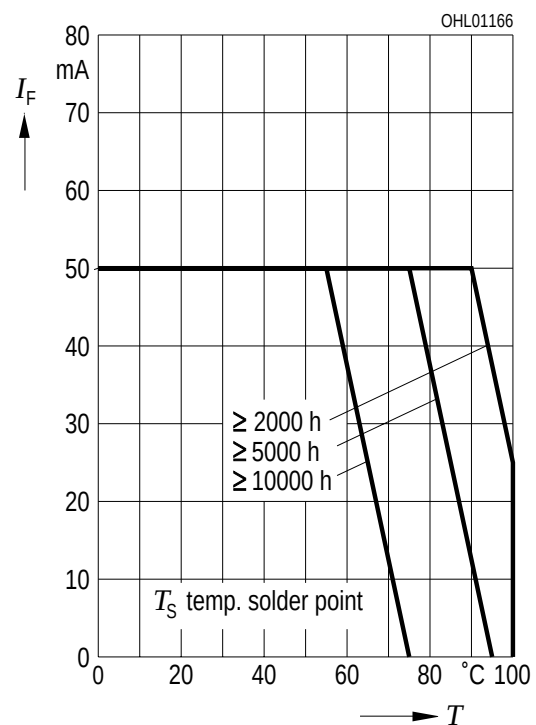
$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$
Max. Permissible Forward Current



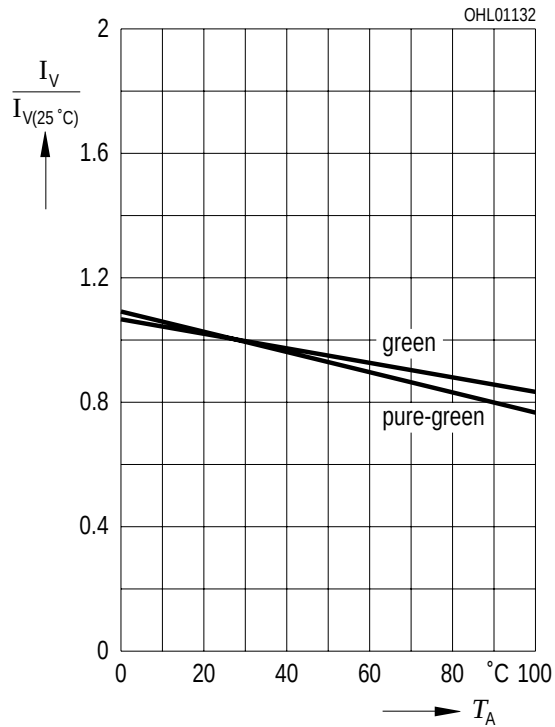
Maximal zulässiger Durchlassstrom $I_F = f(T)$
Max. Permissible Forward Current



Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$

Relative Luminous Intensity

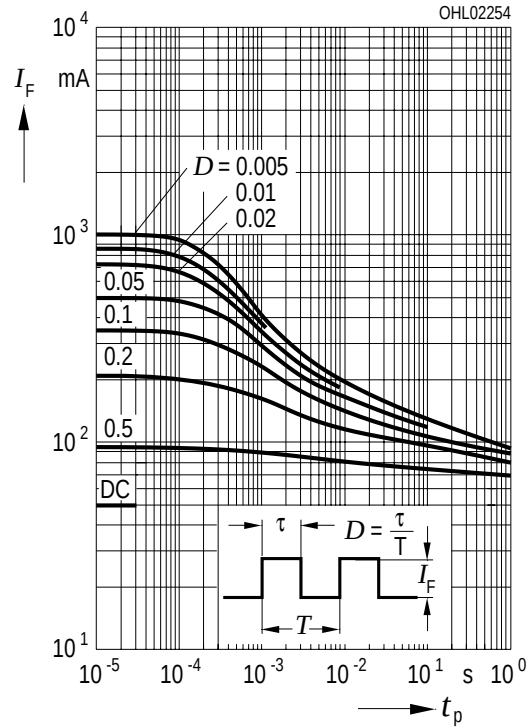
$I_F = 50 \text{ mA}$



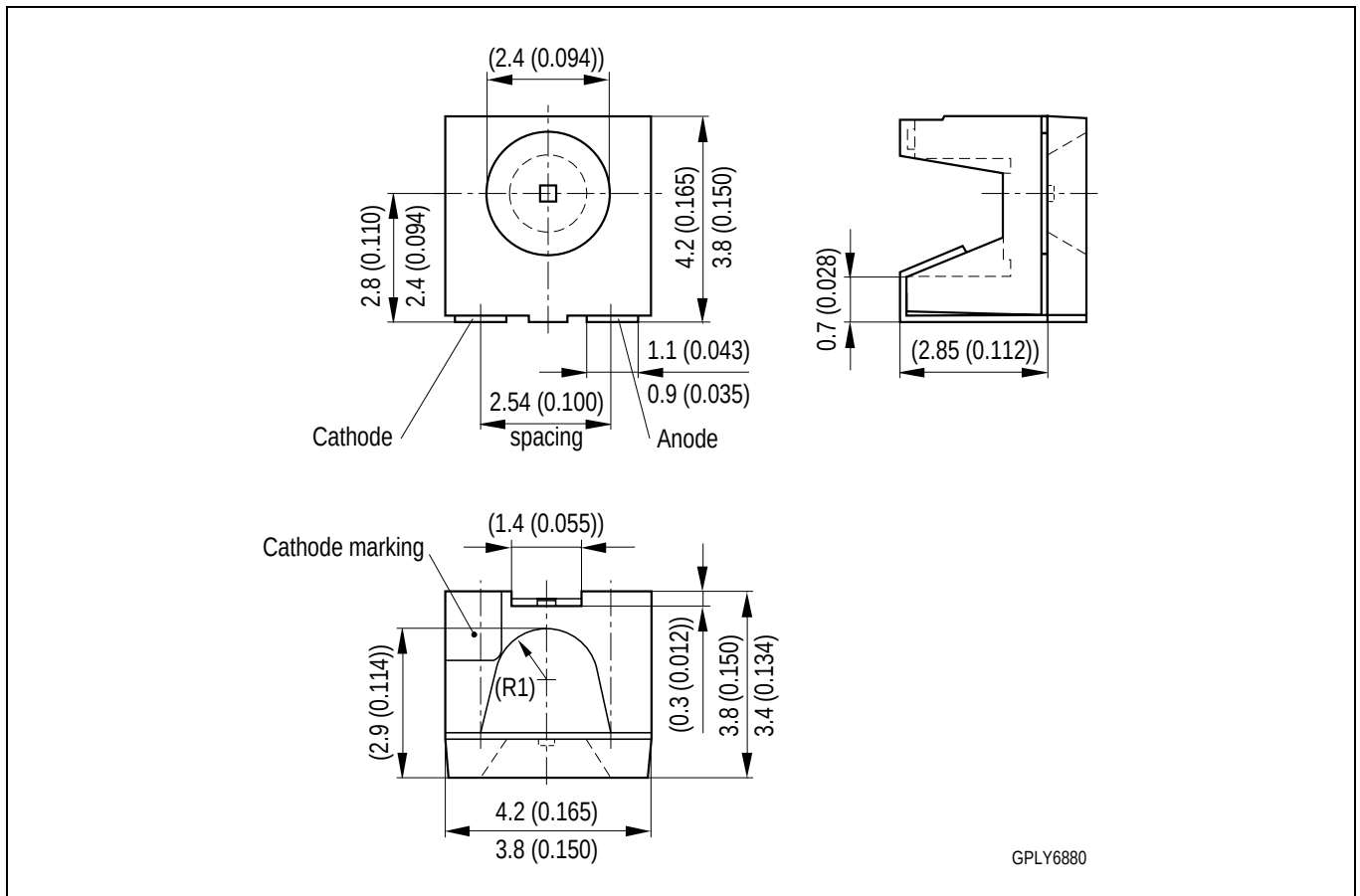
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible Pulse Handling Capability

Duty cycle $D = \text{parameter}$, $T_A = 25^\circ\text{C}$



Maßzeichnung Package Outlines

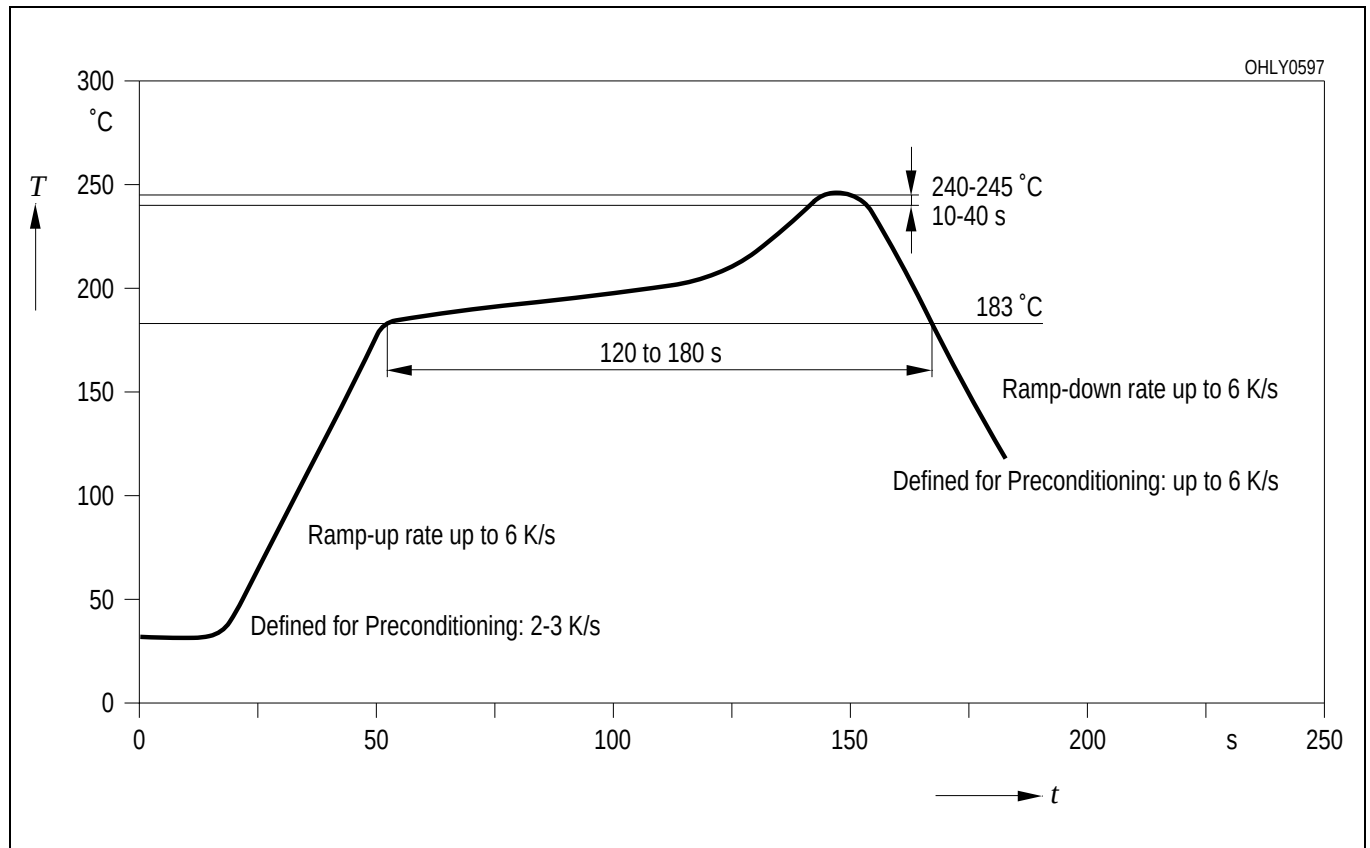


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

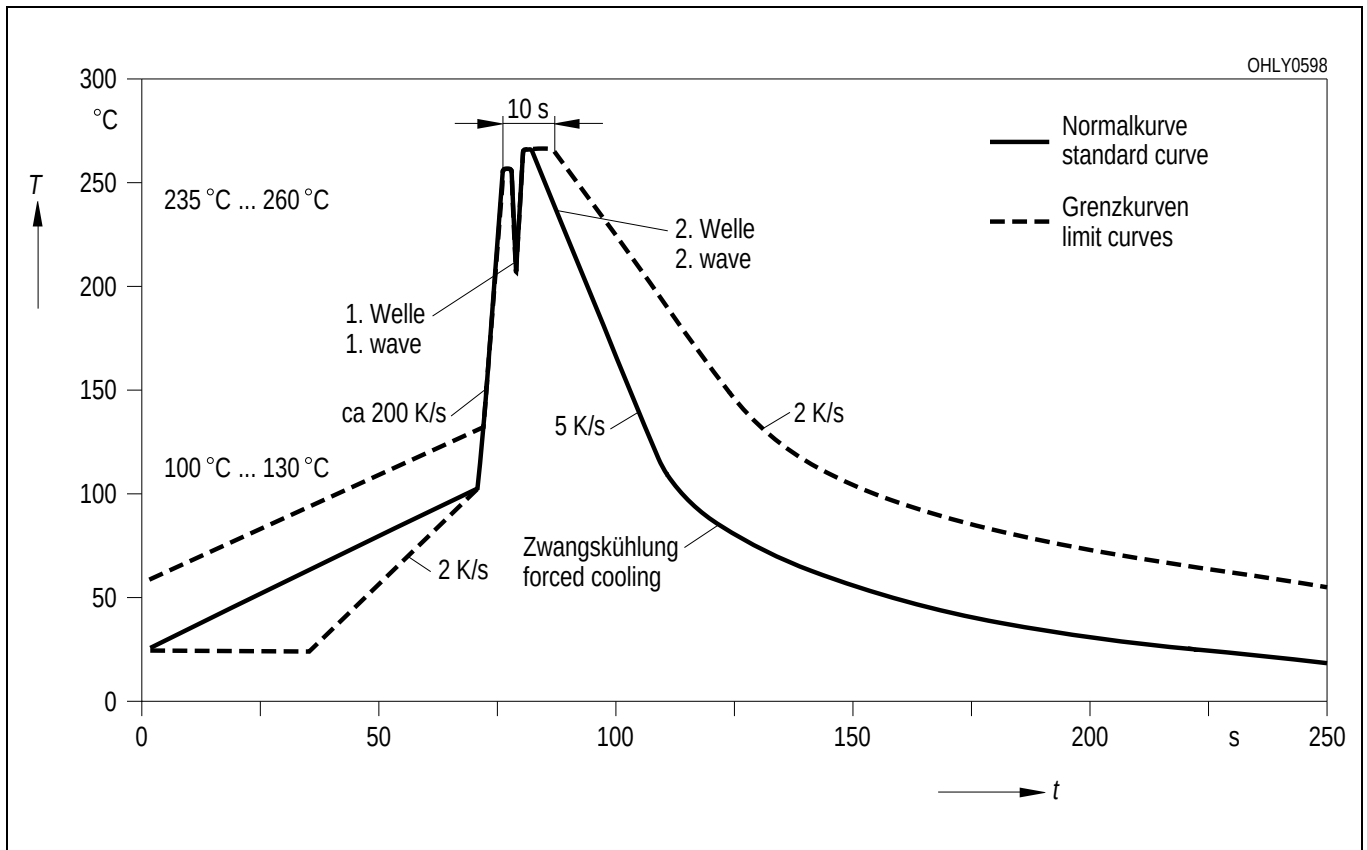
Kathodenkennung: abgeschrägte Ecke
Cathode mark: bevelled edge
Gewicht / Approx. weight: 40 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

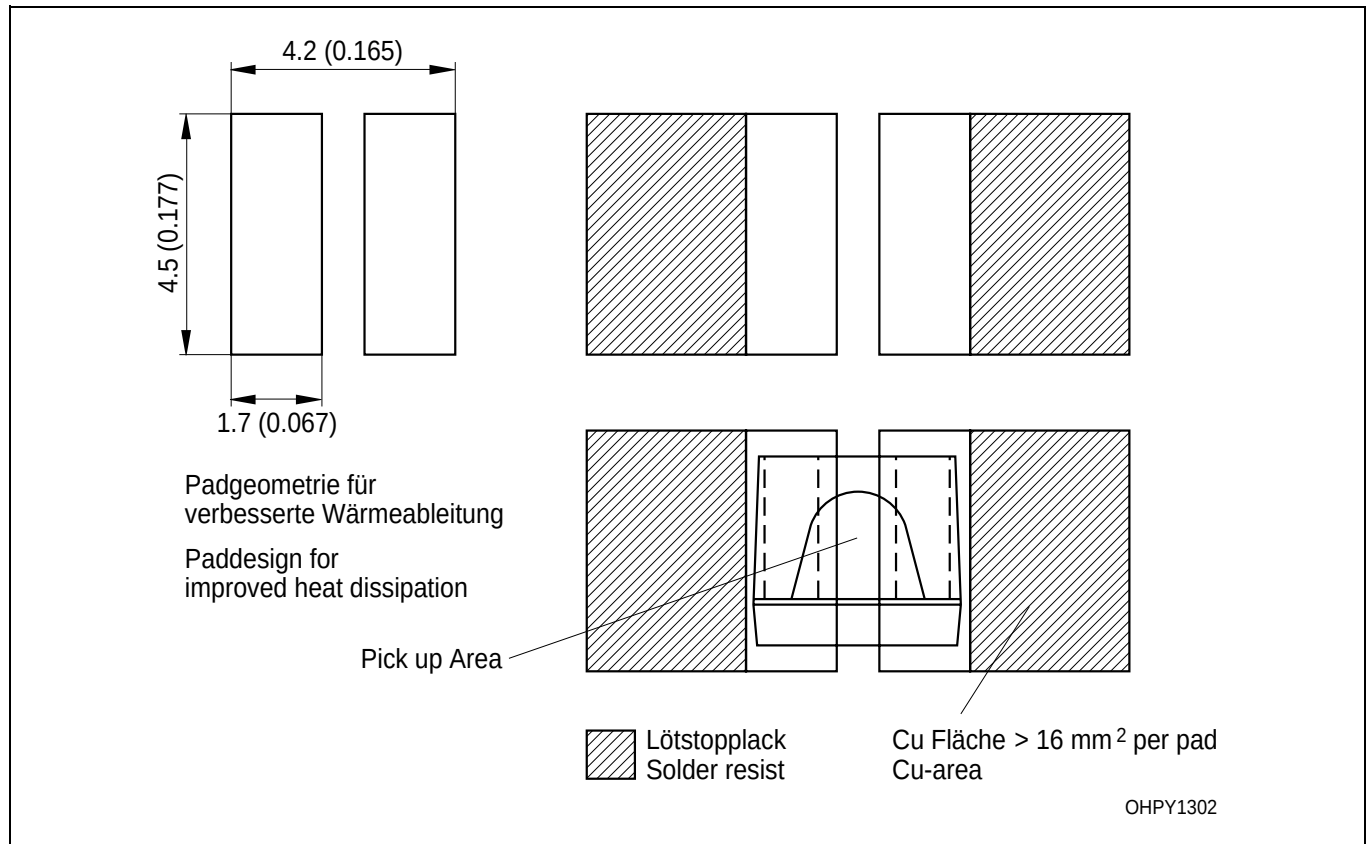
IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)

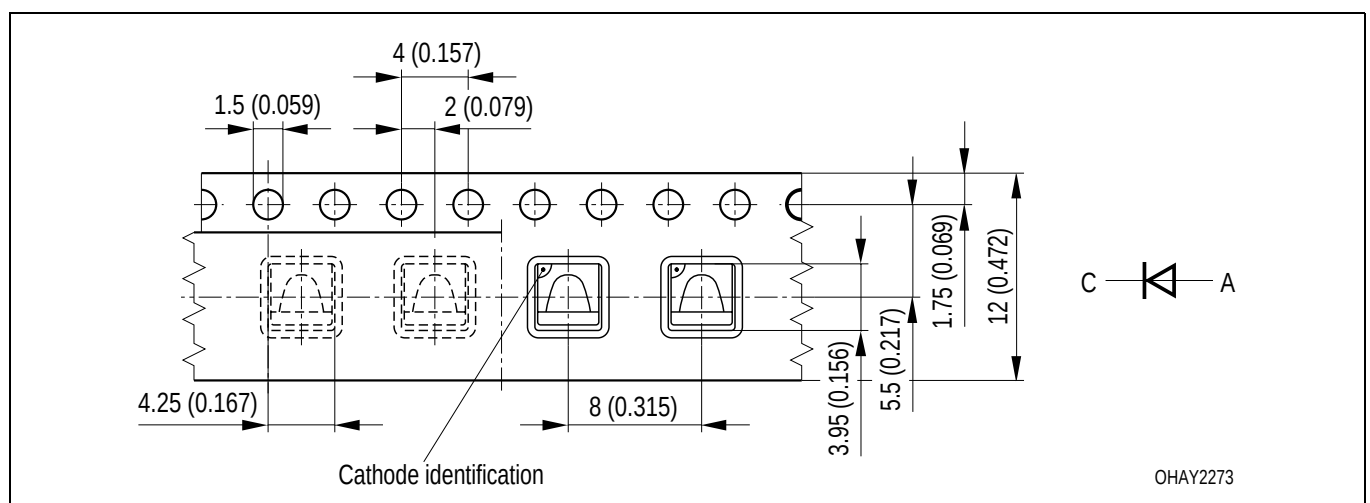


Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Gurtung / Polarität und Lage Verpackungseinheit 2000/Rolle, ø330 mm
Method of Taping / Polarity and Orientation Packing unit 2000/reel, ø330 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2001-05-07

Previous Version: 2001-03-12

Page	Subjects (major changes since last revision)
12	Recommended Solder Pad

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